

### **General Description**

The MAX3346E bidirectional transceiver converts logiclevel signals to USB signals, and USB signals to logiclevel signals. The MAX3346E includes the 1.5k $\Omega$  USB pullup resistor internally, and supports both full-speed (12Mbps) and low-speed (1.5Mbps) USB operation. The device has built-in ±15kV ESD protection circuitry to guard the USB I/O pins, D+ and D-.

The MAX3346E operates with V<sub>L</sub> voltages as low as 1.65V, ensuring compatibility with low-voltage ASICs. The device features a logic-selectable suspend mode that lowers current draw to less than 40µA. The MAX3346E has an enumerate function that allows devices to logically disconnect while plugged in. The MAX3346E is fully compliant with USB specification 1.1, and the full-speed and low-speed operation under USB specification 2.0.

The MAX3346E is available in the miniature 4 x 4 chipscale package (UCSPTM), as well as the small 14-pin TSSOP, and is rated for the -40°C to +85°C extended temperature range.

### **Applications**

Cell Phones

PC Peripherals

**Data Cradles** 

**PDAs** 

MP3 Players

## **Features**

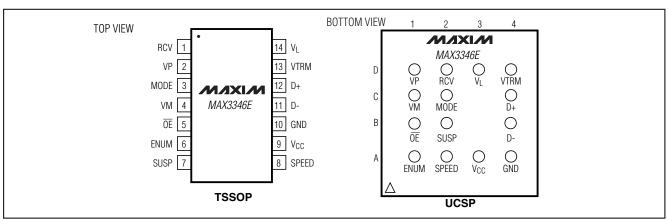
- ♦ ±15kV ESD Protection on D+ and D-
- ♦ Internal Linear Regulator Allows Direct Powering from the USB Cable
- ♦ Internal 1.5kΩ Pullup Resistor for Low/Full-Speed Operation
- ♦ Supports Low-Speed and Full-Speed USB Communications
- ♦ Complies with USB Specification Revision 1.1 and 2.0 (Low Speed and Full Speed)
- **♦ Three-State Outputs**
- ♦ Enumerate Input—Allows USB Connection through Software
- ♦ No Power-Supply Sequencing Required
- ♦ Operates with V<sub>L</sub> of 1.65V to 3.6V, Ensuring Compatibility with Low-Voltage ASICs
- **♦** Available in Miniature Chip-Scale Package

### **Ordering Information**

PART	TEMP RANGE	PIN-PACKAGE
MAX3346EEUD	-40°C to +85°C	14 TSSOP
MAX3346EEBE-T	-40°C to +85°C	4 x 4 UCSP

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## **Pin Configurations**



NIXIN

Maxim Integrated Products 1

### **ABSOLUTE MAXIMUM RATINGS**

(All voltages referenced to GND, u	ınless otherwise noted.)
Supply Voltage (VCC)	0.3V to +6V
Output of Internal Regulator (VTRI)	1)0.3V to (V <sub>CC</sub> + 0.3V)
Input Voltage (D+, D-)	0.3V to +6V
System Supply Voltage (V <sub>L</sub> )	0.3V to +6V
RCV, SUSP, VM, VP, MODE,	
OE, SPEED, ENUM	0.3V to (V <sub>L</sub> + 0.3V)
Short-Circuit Current (D+, D-)	
to V <sub>CC</sub> or GND (Note 1)	Continuous
Maximum Continuous Current (all	other pins)±15mA

Continuous Power Dissipation ( $T_A = +70^{\circ}C$ )	
4 x 4 UCSP (derate 7.4mW/°C above +70°C)	589mW [B16-2]
14-Pin TSSOP (derate 9.1mW/°C above +70°C)	727mW [U14-1]
Operating Temperature Range	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	
Lead Temperature (soldering, 10s)	
Bump Temperature (soldering) Reflow	+235°C

**Note 1:** External 23.7 $\Omega$  resistors connected to D+ and D-.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ELECTRICAL CHARACTERISTICS**

 $(V_{CC} = +4V \text{ to } +5.5V, \text{GND} = 0, \text{VTRM} = +3.0V \text{ to } +3.6V, \text{V}_L = +1.65V \text{ to } +3.6V, \text{T}_A = \text{T}_{MIN} \text{ to T}_{MAX}, \text{ unless otherwise noted.}$  Typical values are at  $V_{CC} = +5V, \text{V}_L = +2.5V, \text{T}_A = +25^{\circ}C.)$  (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
SUPPLY INPUTS (VCC, VTRM, V	'L)					
Regulated Supply Voltage	V <sub>V</sub> TRM	Internal regulator	3.0	3.3	3.6	V
V <sub>L</sub> Input Range			1.65		3.60	V
V <sub>CC</sub> Input Range			4.0		5.5	V
Operating V <sub>CC</sub> Supply Current	Ivcc	Full-speed transmitting/receiving at 12Mbps, C <sub>L</sub> = 50pF on D+ and D-			8	mA
Operating V <sub>L</sub> Supply Current	IVL	Full-speed transmitting/receiving at 12Mbps			6	mA
Full-Speed Idle and SE0 Supply	l	Full-speed idle: $V_{D+} > 2.7V$ , $V_{D-} < 0.3V$		340	450	^
Current	IVCC(IDLE)	SE0: $V_{D+} < 0.3V$ , $V_{D-} < 0.3V$		390	500	μΑ
Static V <sub>L</sub> Supply Current	IVL(STATIC)	Full-speed idle, SE0, or suspend mode			5	μΑ
Suspend Supply Current	IVCC(SUSP)	$SUSP = \overline{OE} = high$			40	μΑ
Disable-Mode Supply Current	Ivcc(DIS)	V <sub>L</sub> = GND or open			20	μΑ
D+/D- Disable-Mode Load Current	I <sub>D_(DIS)</sub>	$V_L = GND \text{ or open, } V_{D} = 0 \text{ or } +5.5V$			5	μΑ
Sharing-Mode V <sub>L</sub> Supply Current	IVL(SHARING)	$V_{CC} = GND$ or open, $\overline{OE} = low$ , $SUSP = high$			20	μА
D+/D- Sharing-Mode Load Current	ID_(SHARING)	V <sub>CC</sub> = GND or open, V <sub>D</sub> _ = 0 or +5.5V			20	μА
LINEAR REGULATOR						
External Capacitor	Cout	Compensation of linear regulator	1			μF

### **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{CC} = +4V \text{ to } +5.5V, \text{GND} = 0, \text{VTRM} = +3.0V \text{ to } +3.6V, \text{V}_{L} = +1.65V \text{ to } +3.6V, \text{T}_{A} = \text{T}_{MIN} \text{ to T}_{MAX}, \text{ unless otherwise noted.}$  Typical values are at  $V_{CC} = +5V, \text{V}_{L} = +2.5V, \text{T}_{A} = +25^{\circ}C.)$  (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
ESD PROTECTION (D+, D-)			•			
Human Body Model				±15		kV
IEC 1000-4-2 Air-Gap Discharge				±10		kV
IEC 1000-4-2 Contact Discharge				±8		kV
LOGIC-SIDE I/O						
Input High Voltage	V <sub>IH</sub>	VP, VM, SUSP, SPEED, $\overline{\text{OE}}$ , MODE, ENUM	(2/3) x V <sub>L</sub>			V
Input Low Voltage	VIL	VP, VM, SUSP, SPEED, $\overline{\text{OE}}$ , MODE, ENUM			0.4	V
Output High Voltage	VoH	ISOURCE = +2mA, RCV, VP, VM	V <sub>L</sub> - 0.4			V
Output Low Voltage	V <sub>OL</sub>	I <sub>SINK</sub> = -2mA, RCV, VP, VM			0.4	V
Input Leakage Current		$VP$ , $VM$ , $SUSP$ , $ENUM$ , $\overline{OE}$ , $MODE = 0$ or $V_L$			±1	μΑ
USB-SIDE I/O						
Output-Voltage Low	Vold	$R_L = 1.5k\Omega$ from D+ or D- to 3.6V			0.3	V
Output-Voltage High	Vohd	$R_L = 15k\Omega$ from D+ and D- to GND	2.8		3.6	V
Input Impedance	Z <sub>IN</sub>	V <sub>D</sub> _ = 0 or +3.6V, ENUM = 0, three-state driver	1			МΩ
Single-Ended Input-Voltage High	VIH		2.0			V
Single-Ended Input-Voltage Low	VIL				0.8	V
D+, D- Receiver Hysteresis				200		mV
Driver Output Impedance	Rout		4.6		16.0	Ω
Internal Resistor	Rpullup		1.410	1.5	1.540	kΩ
Input Common-Mode Voltage			0.8		2.5	V
Differential Input Sensitivity	_		200	_		mV

### **TIMING CHARACTERISTICS**

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PARAMETER	SYMBOL	CONDITIONS		TYP	MAX	UNITS			
SPEED INDEPENDENT TIMING CHARACTERISTICS									
OE to VP/VM Three-State Delay Disable Time	t <sub>PVZ</sub>	Figures 1a and 4a			20	ns			
OE to VP/VM Delay Enable Time	tPZV	Figures 1a and 4a			25	ns			
D+/D- to RCV Propagation Delay	tpLH	C <sub>L</sub> = 25pF, Figures 4b and 5			18	ns			
D+/D- to RCV Propagation Delay	tphL	C <sub>L</sub> = 25pF, Figures 4b and 5			18	ns			



### **TIMING CHARACTERISTICS (continued)**

 $(V_{CC} = +4V \text{ to } +5.5V, \text{ GND} = 0, \text{ VTRM} = +3.0V \text{ to } 3.6V, \text{ } V_{L} = +1.65V \text{ to } +3.6V, \text{ } T_{A} = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted. Typical values are at } V_{CC} = +5V, \text{ } V_{L} = +2.5V, \text{ } T_{A} = +25^{\circ}\text{C.}) \text{ (Note 2)}$ 

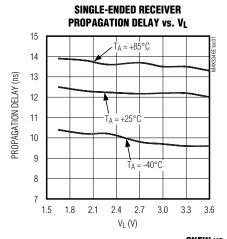
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
D+/D- to VP/VM Propagation	tpLH	C <sub>L</sub> = 25pF, Figures 4b and 5			18	no	
Delay	tphl	C <sub>L</sub> = 25pF, Figures 4b and 5			18	ns	
FULL-SPEED TIMING CHARACT	ERISTICS						
OE to Transmit Delay Enable Time	t <sub>PZD</sub>	(Figures 1b, 4d)			20	ns	
OE to Driver Three-State Delay Disable Time	tPDZ	(Figures1b, 4d)			20	ns	
VP/VM to D+/D- Propagation	tpLH	(Figures 3, 4c)			18		
Delay (MODE = 1)	tphl	(Figures 3, 4c)			18	ns	
VP to D+/D- Propagation Delay	t <sub>PHL0</sub>	C <sub>L</sub> = 50pF (Figures 2, 4c)			20		
(MODE = 0)	t <sub>PLH0</sub>	C <sub>L</sub> = 50pF (Figures 2, 4c)			20	ns	
D+, D- Rise Time	t <sub>R</sub>	$C_L = 50pF$ , 10% to 90% of IV <sub>OH</sub> - V <sub>OL</sub> I	4		20	ns	
D+, D- Fall Time	tF	$C_L = 50$ pF, 90% to 10% of $IV_{OH} - V_{OL}I$	4		20	ns	
Rise- and Fall-Time Matching (Note 3)	t <sub>R</sub> /t <sub>F</sub>	C <sub>L</sub> = 50pF	90		110	%	
Output-Signal Crossover Voltage (Note 3)	VCRS	C <sub>L</sub> = 50pF	1.3		2.0	V	
LOW-SPEED TIMING CHARACTI	RISTICS						
VP/VM to D+/D- Propagation	tpLH	Figures 3 and 4c, C <sub>L</sub> = 50pF to 600pF	30		250	20	
Delay (MODE = 1)	tphL	Figures 3 and 4c, C <sub>L</sub> = 50pF to 600pF	30		250	ns	
VP to D+/D- Propagation Delay	t <sub>PHL0</sub>	Figures 2 and 4c, C <sub>L</sub> = 50pF to 600pF	30		250	20	
(MODE = 0)	t <sub>PLH0</sub>	Figures 2 and 4c, C <sub>L</sub> = 50pF to 600pF	30		250	ns	
D+/D- Rise Time	t <sub>R</sub>	C <sub>L</sub> = 50pF to 600pF	75		300	ns	
D+/D- Fall Time	tF	C <sub>L</sub> = 50pF to 600pF	75		300	ns	
Rise- and Fall-Time Matching	t <sub>R</sub> /t <sub>F</sub>	$C_L = 50pF$ to $600pF$	80		125	%	
Output-Signal Crossover Voltage	Vcrs	C <sub>L</sub> = 50pF to 600pF	1.3		2.0	V	

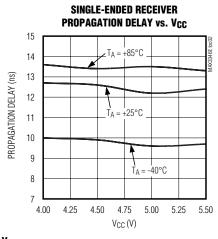
Note 2: Parameters are 100% production tested at +25°C, limits over temperature are guaranteed by design.

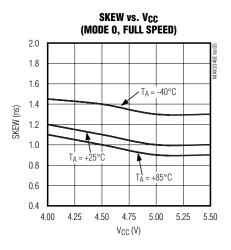
Note 3: Guaranteed by design, not production tested.

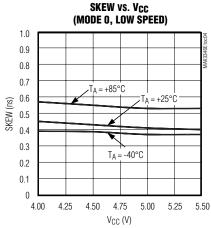
# **Typical Operating Characteristics**

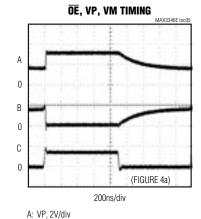
 $(V_{CC} = +5V, V_L = +3.3V, T_A = +25^{\circ}C, unless otherwise noted.)$ 

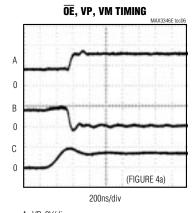


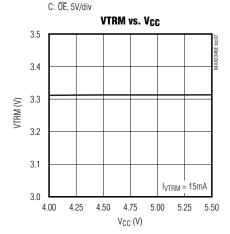










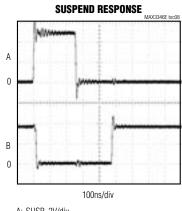


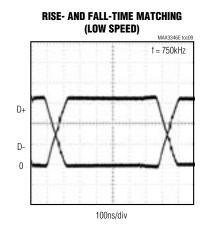
B: VM, 2V/div

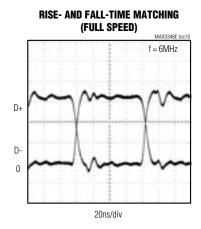
A: VP, 2V/div B: VM, 2V/div C: OE, 5V/div

# **Typical Operating Characteristics (continued)**

 $(V_{CC} = +5V, V_L = +3.3V, T_A = +25^{\circ}C, unless otherwise noted.)$ 







A: SUSP, 2V/div B: RCV, 2V/div

## **Pin Description**

Р	PIN		INPUT/	FUNCTION			
TSSOP	UCSP	NAME	OUTPUT				
1	D2	RCV	Output	Receiver Output. Single-ended CMOS output. RCV responds to the differential input on D+ and D- (see Table 3).			
2	D1	VP	Input/ Output				
3	C2	MODE	Input	Mode Control Input. Selects single-ended (mode zero) or differential (mode one) input for the system side when converting logic-level signals to USB-level signals. If MODE is forced high, mode one is selected. If MODE is forced low, mode zero is selected (see Table 3).			
4	C1	VM	Input/ Output	System-Side Data Input/Output. Drive $\overline{OE}$ high to make VM a receiver output. Drive $\overline{OE}$ low to make VM a driver input (see Table 3).			
5	B1	ŌĒ	Input	Output Enable. Drive $\overline{OE}$ high to enable the receiver. Drive $\overline{OE}$ low to enable the driver input.			
6	A1	ENUM	Input	Enumerate Input. Drive ENUM low to disconnect the internal 1.5k $\Omega$ resistor, and enumerate the USB. With ENUM high, the internal 1.5k $\Omega$ resistor is connected to either D+ or D-, depending on the state of SPEED.			

## Pin Description (continued)

Р	IN	NAME	INPUT/	FUNCTION
TSSOP	UCSP	NAME	OUTPUT	FUNCTION
7	B2	SUSP	Input	Suspend Input. Drive SUSP low for normal operation. Force SUSP high for low-power state. In low-power state RCV is low, D+/D- are high impedance if $\overline{\text{OE}}$ is floating, and VP/VM are active outputs.
8	A2	SPEED	Input	USB Transmission Speed Select Input. If SPEED is forced high, full speed (12Mbps) is selected and the internal 1.5k $\Omega$ pullup resistor is connected to D+. If SPEED is forced low, low speed (1.5Mbps) is selected and the internal 1.5k $\Omega$ pullup resistor is connected to D
9	АЗ	VCC	Power	USB-Side Power-Supply Input. Connect V <sub>CC</sub> to the incoming USB power supply. Bypass V <sub>CC</sub> to GND with a 1µF ceramic capacitor.
10	A4	GND	Power	Ground
11	B4	D-	Input/ Output	USB Differential Data Input/Output. Connect to the USB's D- signal through a $24.3\Omega \pm 1\%$ resistor.
12	C4	D+	Input/ Output	USB Differential Data Input/Output. Connect to the USB's D+ signal through a $24.3\Omega$ ±1% resistor.
13	D4	VTRM	Power	Regulated Output Voltage. 3.3V output derived from the $V_{CC}$ input. Bypass VTRM to GND with a 1 $\mu$ F (or more) low-ESR capacitor, such as ceramic or plastic film types.
14	D3	VL	Power	System-Side Power-Supply Input. Connect to the system's logic-level power supply, 1.65V to 3.6V. Bypass to GND with a 0.1µF capacitor.
_	B3, C3	_	_	Not populated. The solder sphere is omitted from these locations (see the <i>Package Information</i> ).

### Detailed Description

The MAX3346E is a bidirectional transceiver that converts single-ended or differential logic-level signals to differential USB signals, and converts differential USB signals to single-ended or differential logic-level signals. The MAX3346E includes an internal  $1.5k\Omega$  pullup resistor that can be connected to either D+ or D- for full-speed or low-speed operation (see the *Functional Diagram*). The MAX3346E can be energized without concern about power-supply sequencing. Additionally, the USB I/O, D+ and D-, are ESD protected to  $\pm 15kV$ . The MAX3346E can get its USB-side power, VCC,

directly from the USB connection, and can operate with system-side power,  $V_L$ , down to 1.65V and still meet the USB physical layer specifications. The MAX3346E supports both full-speed (12Mbps) and low-speed (1.5Mbps), USB specification 1.1 operation.

The MAX3346E has an enumerate feature that works when power is on. Driving ENUM low disconnects the internal 1.5k $\Omega$  pullup resistor from both D+ and D-, reenumerating the USB. This is useful if changes in communication protocol are required while power is applied, and while the USB cable is connected.

## Applications Information

### **Power-Supply Configurations**

#### Normal Operating Mode

Connect  $V_L$  and  $V_{CC}$  to system power supplies (Table 1). Connect  $V_L$  to a +1.65V to +3.6V supply. Connect  $V_{CC}$  to a +4.0V to +5.5V supply. Alternatively, the MAX3346E can derive power from a single Li+ battery. Connect the battery to  $V_{CC}$ . VTRM remains above +3.0V for  $V_{CC}$  as low as +3.1V.

Additionally, the MAX3346E can derive power from a 3.3V ±10% voltage regulator. Connect V<sub>CC</sub> and VTRM to an external +3.3V voltage regulator.

#### Disable Mode

Connect V<sub>CC</sub> to a system power supply and leave V<sub>L</sub> unconnected or connect to GND. D+ and D- enter a tristate mode and V<sub>CC</sub> consumes less than 20µA of supply current. D+ and D- withstand external signals up to +5.5V in disable mode (Table 2).

#### Sharing Mode

Connect  $V_L$  to a system power supply and leave  $V_{CC}$  (or  $V_{CC}$  and  $V_{VTRM}$ ) unconnected or connect to GND. D+ and D- enter a tri-state mode, allowing other circuitry to share the USB D+ and D- lines, and  $V_L$  consumes less than  $20\mu A$  of supply current. D+ and D- withstand external signals up to +5.5V in sharing mode (Table 2).

#### **Device Control**

OE

 $\overline{\text{OE}}$  controls the direction of communication through the device. With  $\overline{\text{OE}}$  low, the MAX3346E transfers data from the system side to the USB side. With  $\overline{\text{OE}}$  high, the MAX3346E transfers data from the USB side to the system side.

#### **ENUM**

The MAX3346E allows software control of USB enumeration. USB specification 1.1 requires a  $1.5 k\Omega$  pullup resistor to D+ or D- to set the transmission speed (see the SPEED section). Enumerating the USB requires removing the  $1.5 k\Omega$  resistor from the circuit, and is accomplished with the MAX3346E by driving ENUM low. With ENUM high, the voltage at SPEED determines how the internal resistor is connected (see the  $Functional\ Diagram$ ).

#### MODE

MODE is a control input that selects whether differential or single-ended logic signals are recognized by the system side of the MAX3346E (Table 3).

If MODE is forced high, differential input is selected. With differential input selected, outputs D+ and D- follow the differential inputs at VP and VM. If VP and VM are both forced low, an SE0 condition is forced on the USB.

Drive MODE and VM low for single-ended input mode. With single-ended input selected, the differential signal on D+ and D- is controlled by VP. If VM is high when MODE is low, D- and D+ are both low, forcing an SE0 condition.

**Table 1. Power-Supply Configurations** 

V <sub>CC</sub> (V)	VTRM (V)	V <sub>L</sub> (V)	CONFIGURATION	NOTES
+4.0 to +5.5	+3.3 Output	+1.65 to +3.6	Normal mode	
+3.1 to +4.5	+3.3 Output	+1.65 to +3.6	Battery supply	_
+3.0 to +3.6	+3.0 to +3.6 Input	+1.65 to +3.6	Voltage regulator supply	
GND or floating	Output	+1.65 to +3.6	Sharing mode	Table 2
+3.0 to +5.5	Output	GND or floating	Disable mode	Table 2

Table 2. Disable-Mode and Sharing-Mode Configurations

INPUTS/OUTPUTS	DISABLE MODE	SHARING MODE
Vcc/VTRM	<ul> <li>+5V input/+3.3V output</li> <li>+3.3V input/+3.3V output</li> <li>+3.7V input/+3.3V output</li> </ul>	Floating or connected to GND
VL	Floating or connected to GND	+1.65V to +3.6V input
D+ and D-	High impedance	High impedance
SPEED, SUSP, OE, ENUM	High impedance	High impedance

### **Timing Diagrams**

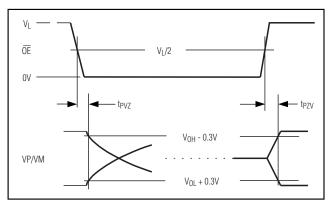


Figure 1a. Enable and Disable Timing, Receiver

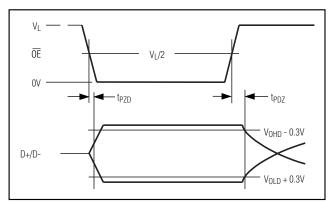


Figure 1b. Enable and Disable Timing, Transmitter

#### SUSP

SUSP, or suspend, is a control input. When SUSP is forced high the MAX3346E enters a low-power state. In this state, the quiescent supply current into VCC is less than  $40\mu A.$  In this mode, RCV is forced low, and D+ and D- are high-impedance inputs (Table 3d).

In suspend mode, data can only be transmitted with full-speed slope control.

#### **SPEED**

SPEED is a control input that selects between low-speed (1.5Mbps) and full-speed (12Mbps) USB transmission. Internally, it selects whether the 1.5k $\Omega$  pullup resistor is connected to D+ (full-speed) or D- (low-speed) (*Functional Diagram*). Force SPEED high to select full speed, or force SPEED low to select low speed.

#### **VTRM**

VTRM is the 3.3V output of the internal linear voltage regulator. The regulator is used to power the internal portions of the USB side of the MAX3346E. The VTRM

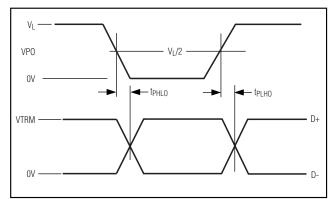


Figure 2. Mode 0 Timing

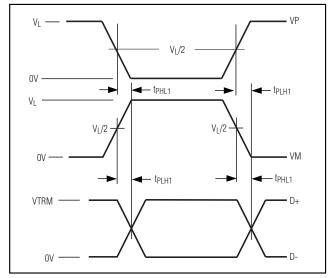


Figure 3. Mode 1 Timing

regulator's supply input is V<sub>CC</sub>. Connect a 1.0 $\mu$ F (or greater) ceramic or plastic capacitor from VTRM to GND, as close to VTRM as possible. Do not use VTRM to provide power to external circuitry.

#### D+ and D-

D+ and D- are the transceiver I/O connections, and are ESD protected to ±15kV using the Human Body Model, making the MAX3346E ideal for applications where a robust transmitter is required.

#### Vcc

Bypass VCC to GND with a  $1\mu F$  capacitor. Place the  $1\mu F$  capacitor as close as possible to the MAX3346E.

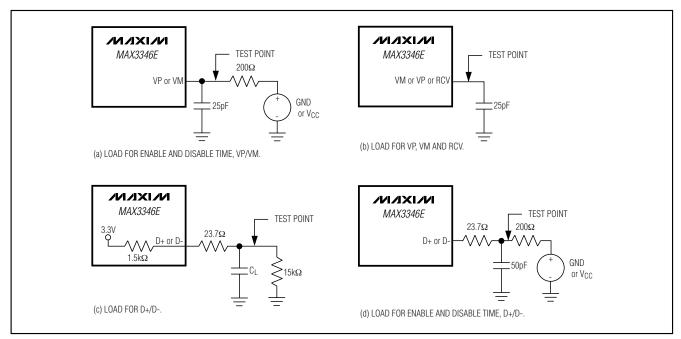


Figure 4. Test Circuits

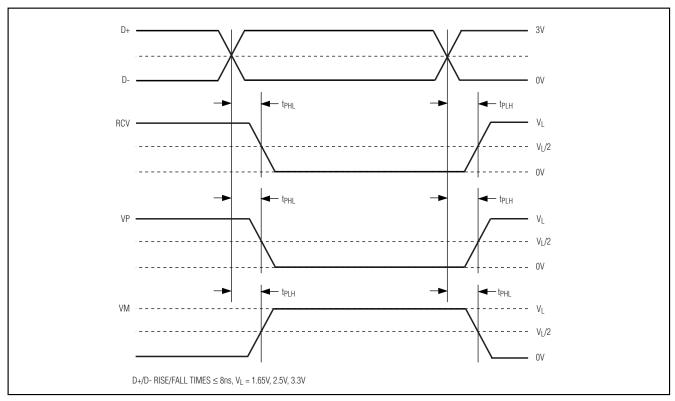


Figure 5. D+/D- to RCV, VP, VM Propagation Delays

Table 3a. Truth Table, Transmit (MODE = 0)

$\overline{\text{OE}} = 0 \text{ (TRANSMIT)}$								
IN	DECLU T							
VP	VM	D+	D-	RCV	RESULT			
0	0	0	1	0	Logic 0			
0	1	0	0	RCV*	SE0			
1	0	1	0	1	Logic 1			
1	1	0	0	X	SE0			

<sup>\*</sup>RCV denotes the signal level on output RCV just before SE0 state occurs. This level is stable during the SE0 period.

### **Table 3b. Truth Table, Transmit (MODE = 1)**

OE = 0 (TRANSMIT)								
INPUT		ОИТРИТ			DECLUT			
VP	VM	D+	D-	RCV	RESULT			
0	0	0	0	RCV*	SE0			
0	1	0	1	0	Logic 0			
1	0	1	0	1	Logic 1			
1	1	1	1	X	Undefined			

<sup>\*</sup>RCV denotes the signal level on output RCV just before SE0 state occurs. This level is stable during the SE0 period.

### Table 3c. Truth Table, Receive

OE = 1 (RECEIVE)								
INPUT		OUTPUT			DECLUT			
D+	D-	VP	VM	RCV	RESULT			
0	0	0	0	RCV*	SE0			
0	1	0	1	0	Logic 0			
1	0	1	0	1	Logic 1			
1	1	1	1	X	Undefined			

<sup>\*</sup>RCV denotes the signal level on output RCV just before SE0 state occurs. This level is stable during the SE0 period.

### **Table 3d. Function Select**

SUSP	ENUMERATE	ŌĒ	D+/D-	RCV	VP/VM	FUNCTION
0	0	0	Driving	Active	High-Z	Normal driving
0	0	1	High-Z	Active	Active	Normal receiving, RPULLUP disconnected
0	1	0	Driving	Active	High-Z	Normal driving
0	1	1	High-Z	Active	Active	Normal receiving, RPULLUP connected
1	0	0 or 1	High-Z	0	Active	Suspend mode, RPULLUP disconnected
1	1	0 or 1	High-Z	0	Active	Suspend mode, RPULLUP connected

#### **External Components**

#### External Resistors

Two external resistors are required for USB connection, each of them from  $23.7\Omega$  ±1% to  $27.4\Omega$  ±1%, 1/2W (or greater). Place one resistor in series between D+ of the MAX3346E and D+ of the USB connector. Place the other resistor in series between D- of the MAX3346E and D- of the USB connector. The *Typical Operating Circuit* shows these connections.

#### External Capacitors

Four external capacitors are recommended for proper operation. Use a  $0.1\mu F$  ceramic for decoupling  $V_L$ , a  $1\mu F$  ceramic capacitor for decoupling  $V_{CC}$ , and a  $1.0\mu F$  (or greater) ceramic or plastic filter capacitor on VTRM. Return all capacitors to GND.

#### Receiving Data from the USB

Data received from the USB are output to VP/VM and RCV in either of two ways, differentially or single ended. To receive data from the USB, force  $\overline{OE}$  high, and force SUSP low. Differential data arriving at D+/D- appears as differential logic signals at VP/VM, and as a single-ended logic signal at RCV. If both D+ and D- are low, then VP and VM are low, signaling an SEO condition on the bus; RCV retains the last state before SEO (see Table 3).

#### Transmitting Data to the USB

The MAX3346E outputs data to the USB differentially on D+ and D-. The logic driving the signals may be either differential or single ended. For sending differential logic, force MODE high, force  $\overline{\text{OE}}$  and SUSP low, and apply data to VP and VM. If sending single-ended logic, force MODE, SUSP,  $\overline{\text{OE}}$ , and VM low, and apply data to VP. With VP low, D+ is low and D- high, resulting in a logic 0 state. With VP high, D+ is high and D-low, resulting in a logic 1 state (see Table 3).

### **ESD** protection

To protect the MAX3346E against ESD, D+ and D- have extra protection against static electricity to protect the device up to  $\pm 15$ kV. The ESD structures withstand high ESD in all states; normal operation, suspend, and powered down. For the 15kV ESD structures to work correctly, a 1 $\mu$ F or greater capacitor must be connected from VTRM to GND.

ESD protection can be tested in various ways; the D+ and D- input/output pins are characterized for protection to the following limits:

- 1) ±15kV using the Human Body Model.
- 2) ±8kV using the Contact Discharge method specified in IEC 1000-4-2.
- 3) ±10kV using the IEC 1000-4-2 Air-Gap method.

#### **ESD Test Conditions**

ESD performance depends on a variety of conditions. Contact Maxim for a reliability report that documents test setup, test methodology, and test results.

#### **Human Body Model**

Figure 6a shows the Human Body Model, and Figure 6b shows the current waveform it generates when discharged into a low impedance. This model consists of a 100pF capacitor charged to the ESD voltage of interest, which is then discharged into the test device through a  $1.5 \text{k}\Omega$  resistor.

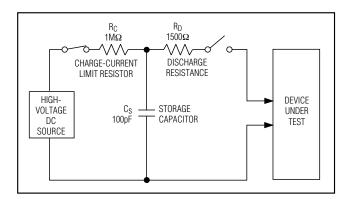


Figure 6a. Human Body ESD Test Models

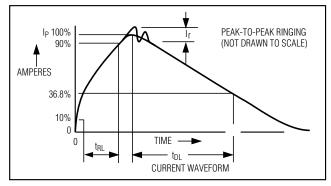


Figure 6b. Human Body Model Current Waveform

#### IEC 1000-4-2

The IEC 1000-4-2 standard covers ESD testing and performance of finished equipment; it does not specifically refer to integrated circuits. The MAX3346E helps to design equipment that meets Level 2 of IEC 1000-4-2, without the need for additional ESD-protection components.

The major difference between tests done using the Human Body Model and IEC 1000-4-2 is a higher peak current in IEC 1000-4-2, because series resistance is lower in the IEC 1000-4-2 model. Hence, the ESD withstand voltage measured to IEC 1000-4-2 is generally lower than that measured using the Human Body Model. Figure 7a shows the IEC 1000-4-2 model.

The Air-Gap Discharge test involves approaching the device with a charged probe. The Contact Discharge method connects the probe to the device before the probe is energized.

#### Machine Model

The Machine Model for ESD tests all pins using a 200pF storage capacitor and zero discharge resistance. Its objective is to emulate the stress caused by contact that occurs with handling and assembly during manufacturing. Of course, all pins require this protection during manufacturing, not just USB inputs and outputs. Therefore, after PC board assembly, the Machine Model is less relevant to I/O ports.

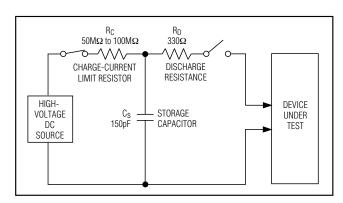
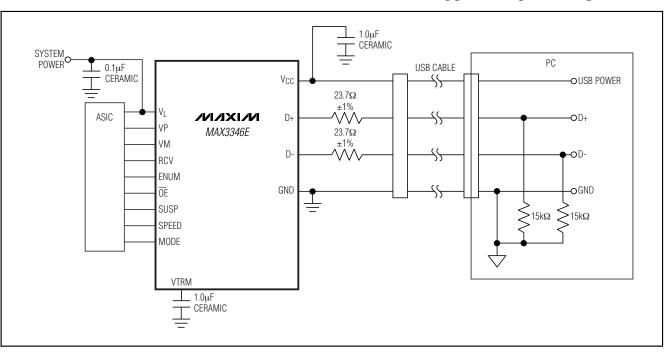


Figure 7a. IEC 1000-4-2 ESD Test Model

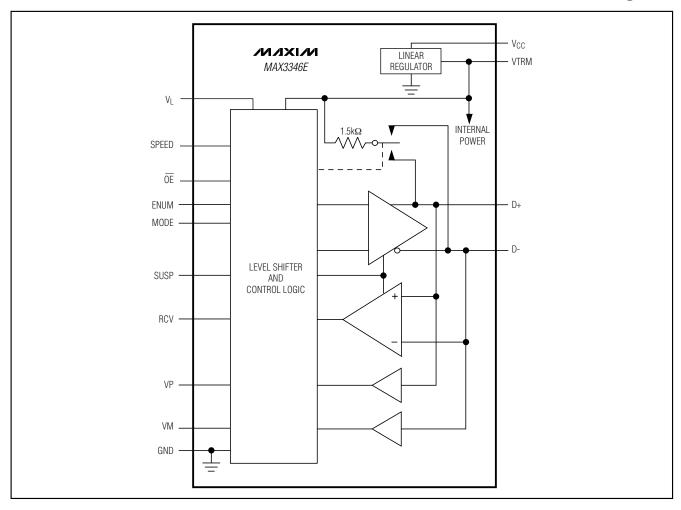
## **UCSP Applications Information**

For the latest application details on UCSP construction, dimensions, tape carrier information, printed circuit board techniques, bump-pad layout, and recommended reflow temperature profile as well as the latest information on reliability testing results, go to the Maxim website at www.maxim-ic.com/ucsp for the Application Note, "UCSP—A Wafer-Level Chip-Scale Package."

## **Typical Operating Circuit**



## Functional Diagram

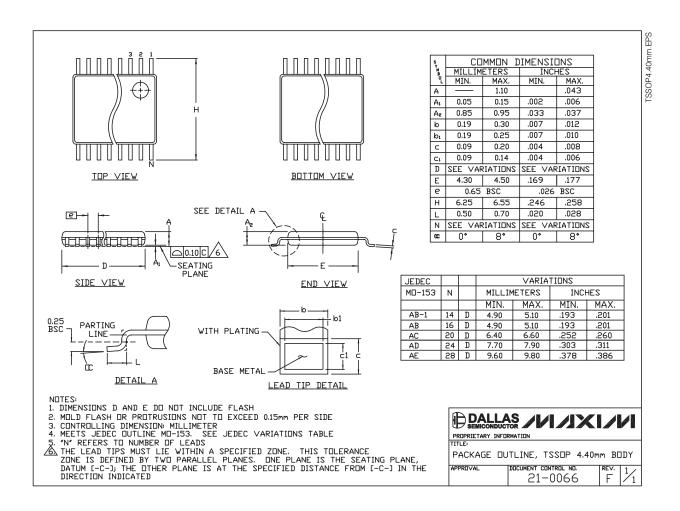


**Chip Information** 

TRANSISTOR COUNT: 2162 PROCESS: BICMOS

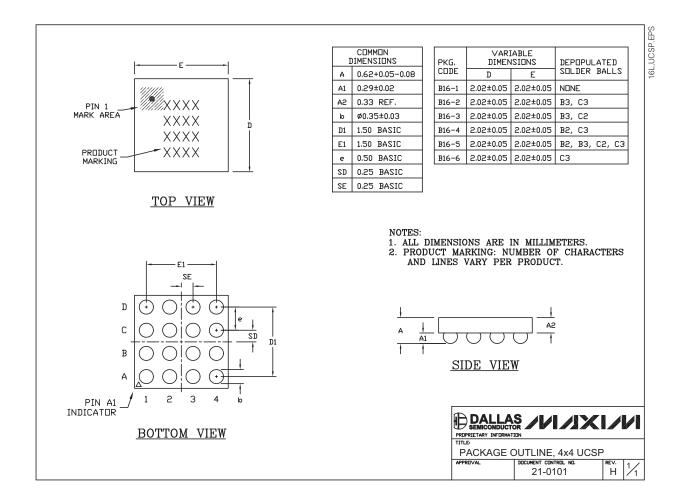
## Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to <a href="https://www.maxim-ic.com/packages">www.maxim-ic.com/packages</a>.)



## Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to <a href="https://www.maxim-ic.com/packages">www.maxim-ic.com/packages</a>.)



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